



## High voltage NPN power transistor

#### **Features**

- High voltage capability
- High DC current gain
- Minimum lot-to-lot spread for reliable operation

### **Applications**

- Switching mode power supply
- Battery charger

#### **Description**

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage withstand capability. The device is designed for use in SMPS and battery charger.

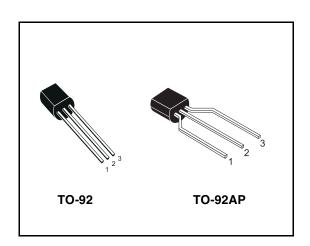


Figure 1. Internal schematic diagram

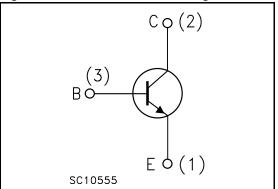


Table 1. Device summary

Order code	Marking	Package	Packaging
STX616	X616	TO-92	Bulk
STX616-AP	X616	TO-92AP	Ammopack

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Electrical characteristics STX616 STX616-AP

## 1 Electrical characteristics

(T<sub>case</sub> = 25°C unless otherwise specified)

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V <sub>CES</sub>	Collector-emitter voltage (V <sub>BE</sub> = 0)	980	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	500	V
V <sub>EBO</sub>	Emitter-base voltage (I <sub>C</sub> = 0)	12	V
I <sub>C</sub>	Collector current	1.5	Α
I <sub>CM</sub>	Collector peak current (t <sub>P</sub> < 5ms)	2.4	Α
I <sub>B</sub>	Base current	0.8	Α
I <sub>BM</sub>	Base peak current (t <sub>P</sub> < 5ms)	1.2	Α
P <sub>tot</sub>	Total dissipation at T <sub>c</sub> = 25°C	2.8	W
T <sub>stg</sub>	Storage temperature	-65 to 150	°C
T <sub>J</sub>	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit	
R <sub>thj-case</sub>	Thermal resistance junction-case	max	44.6	°C/W
R <sub>thj-amb</sub>	Thermal resistance junction-ambient	max	150	°C/W

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## 2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$ 

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector cut-off current (V <sub>BE</sub> =0)	V <sub>CE</sub> = 980V V <sub>CE</sub> = 980V T <sub>c</sub> = 125°C			50 0.5	μA mA
V <sub>CE(sus)</sub> (1)	Collector-emitter sustaining voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 10mA	500			V
V <sub>EBO</sub>	Emitter-base voltage $(I_C = 0)$	I <sub>E</sub> = 1mA	12			V
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage	$I_C = 0.2A$ $I_B = 40 \text{mA}$ $I_C = 1A$ $I_B = 200 \text{mA}$			0.5 1	V V
V <sub>BE(sat)</sub> (1)	Base-emitter saturation voltage	$I_C = 0.2A$ $I_B = 40mA$ $I_C = 1A$ $I_B = 200mA$			1 1.4	V V
h <sub>FE</sub> <sup>(1)</sup>	DC current gain	$\begin{split} & I_{C} = 500 \mu A & V_{CE} = 2V \\ & I_{C} = 200 mA & V_{CE} = 5V \\ & I_{C} = 500 mA & V_{CE} = 5V \\ & I_{C} = 1.5A & V_{CE} = 5V \end{split}$	17 25 12 4			
t <sub>on</sub> t <sub>s</sub>	RESISTIVE LOAD Turn-on time Storage time Fall time	$V_{CC} = 250V$ $I_C = 250mA$ $I_{B1} = 65mA$ $I_{B2} = -130mA$			0.2 5 0.65	μs μs μs
t <sub>on</sub> t <sub>s</sub>	RESISTIVE LOAD Turn-on time Storage time Fall time	$V_{CC} = 250V$ $I_C = 0.8A$ $I_{B1} = 160mA$ $I_{B2} = -0.4A$			1 2.5 0.35	μs μs μs
t <sub>s</sub>	INDUCTIVE LOAD Storage time Fall time	$V_{cl} = 300V$ $I_{C} = 250mA$ $I_{B1} = 65mA$ $I_{B2} = -130mA$ $L = 200\mu H$			5 0.5	μs μs
t <sub>s</sub>	INDUCTIVE LOAD Storage time Fall time	$V_{cl} = 300V$ $I_{C} = 0.8A$ $I_{B1} = 160mA$ $I_{B2} = -0.4A$ $L = 200\mu H$			2.5 0.25	μs μs

Note (1) Pulsed duration = 300  $\mu$ s, duty cycle  $\leq .5\%$ 

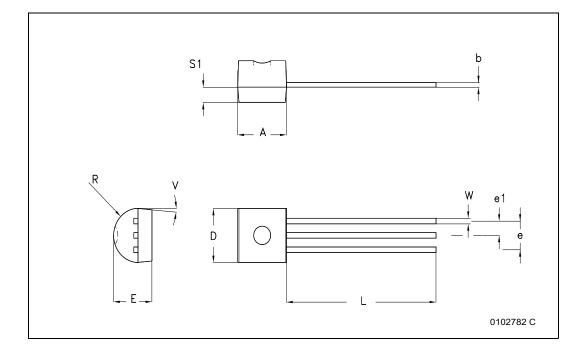
## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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#### **TO-92 BULK SHIPMENT MECHANICAL DATA**

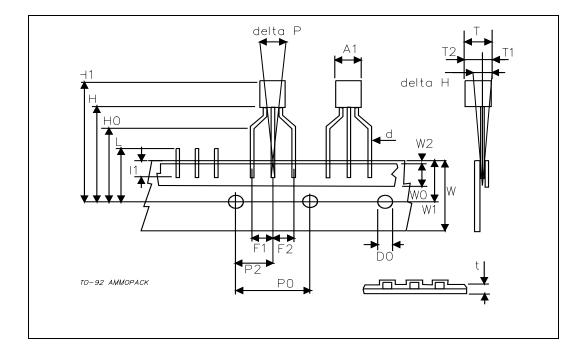
DIM.	mm.				
	MIN.	ТҮР	MAX.		
Α	4.32		4.95		
b	0.36		0.51		
D	4.45		4.95		
E	3.30		3.94		
е	2.41		2.67		
e1	1.14		1.40		
L	12.70		15.49		
R	2.16		2.41		
S1	0.92		1.52		
W	0.41		0.56		
V		5 °			



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#### TO-92 AMMOPACK SHIPMENT (Suffix"-AP") MECHANICAL DATA

DIM	mm.				
DIM.	MIN.	TYP	MAX.		
A1			4.80		
Т			3.80		
T1			1.60		
T2			2.30		
d			0.48		
P0	12.50	12.70	12.90		
P2	5.65	6.35	7.05		
F1,F2	2.44	2.54	2.94		
delta H	-2.00		2.00		
W	17.50	18.00	19.00		
W0	5.70	6.00	6.30		
W1	8.50	9.00	9.25		
W2			0.50		
Н	18.50		20.50		
H0	15.50	16.00	16.50		
H1			25.00		
D0	3.80	4.00	4.20		
t			0.90		
L			11.00		
I1	3.00				
delta P	-1.00		1.00		



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STX616 STX616-AP Revision history

# 4 Revision history

Table 5. Document revision history

Date	Revision	Changes	
06-Jun-2007	1	Initial release.	
22-Oct-2007	2	Added TO-92AP package.	

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